



## TO-220F-2L Plastic-Encapsulate Diode

### MURF20H60L HYPERFAST RECTIFIER,FRED

#### MAIN CHARACTERISTICS

$I_o$	20A
$V_{RRM}$	600V
$T_{rr}$	24ns
$T_j$	175°C
$V_{F(typ)}$	1.1V(@ $T_j=150^\circ\text{C}$ )

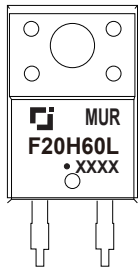
#### FEATURES

- Ultrafast Recovery Times and Low Recovery Loss
- Low Forward Voltage
- Low Reverse Leakage Current

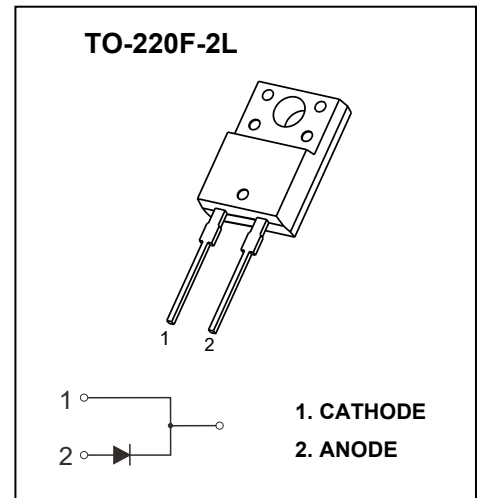
#### APPLICATIONS

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

#### MARKING



MURF20H60L = Device code  
 Solid dot = Green molding compound device  
 if none, the normal device  
 XXXX = Code



#### MAXIMUM RATINGS ( $T_c=25^\circ\text{C}$ unless otherwise noted )

Symbol	Parameter	MURF20H60L	Unit
$V_{RRM}$	Peak Repetitive Reverse Voltage	600	V
$V_R$	DC Blocking Voltage		
$I_{F(AV)}$	Average Forward Current( $T_c=92^\circ\text{C}$ )	20	A
$I_{F(RMS)}$	RMS Forward Current( $T_c=92^\circ\text{C}$ )	28	A
$I_{FSM}$	Non-Repetitive Surge Forward Current (8.3ms )	300	A
$P_D$	Power dissipation	41	W
$R_{\theta JC}$	Thermal Resistance From Junction to Case	3.7	$^\circ\text{C/W}$
$T_j$	Operating Junction Temperature Range	-55 ~ +175	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55 ~ +175	$^\circ\text{C}$

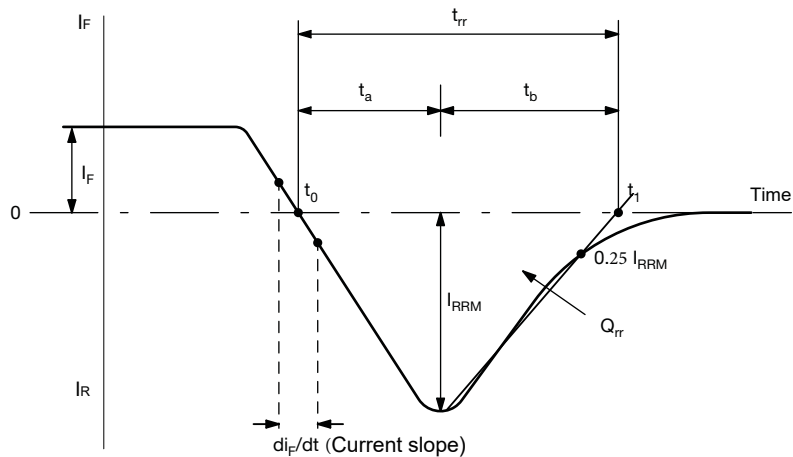
# Typical Characteristics

## ELECTRICAL CHARACTERISTICS ( $T_c=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{(BR)}$	Reverse Voltage	$I_R=100\mu\text{A}$	600			V
$I_R$	Reverse Current	$V_R=600\text{V}$	$T_j=25^\circ\text{C}$		10	$\mu\text{A}$
			$T_j=150^\circ\text{C}$		500	$\mu\text{A}$
$V_F$	Forward Voltage	$I_F=20\text{A}$	$T_j=25^\circ\text{C}$	1.4	1.6	V
			$T_j=150^\circ\text{C}$	1.1		V
$C_{tot}$	Total Capacitance	$V_R=200\text{V}, f=1\text{MHz}$		30		pF
$t_{rr}$	Reverse Recovery time	$I_F=0.5\text{A}, I_R=1\text{A}, I_{rr}=0.25\text{A}$		35		ns
		$I_F=1\text{A}, V_R=30\text{V}, di_F/dt = 200\text{A}/\mu\text{s}$		24		ns

## ELECTRICAL CHARACTERISTICS ( $T_c=25^\circ\text{C}$ unless otherwise specified)

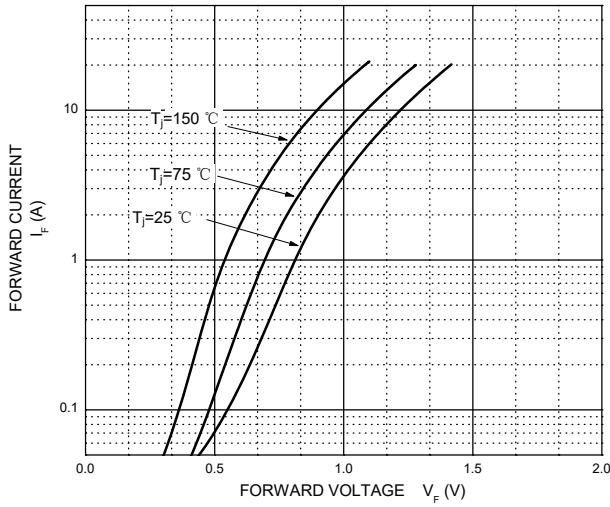
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$t_{rr}$	Reverse Recovery Time	$I_F=20\text{A}, V_R=400\text{V}, di_F/dt=200\text{A}/\mu\text{s}$		72		ns
$I_{RRM}$	Max. Reverse Recovery Current			4.2		A
$Q_{rr}$	Reverse Recovery Charge			183		nC
$t_{rr}$	Reverse Recovery Time	$I_F=20\text{A}, V_R=400\text{V}, di_F/dt=200\text{A}/\mu\text{s}, T_j=125^\circ\text{C}$		102		ns
$I_{RRM}$	Max. Reverse Recovery Current			9		A
$Q_{rr}$	Reverse Recovery Charge			513		nC
$t_{rr}$	Reverse Recovery Time	$I_F=20\text{A}, V_R=400\text{V}, di_F/dt=600\text{A}/\mu\text{s}, T_j=125^\circ\text{C}$		59		ns
$I_{RRM}$	Max. Reverse Recovery Current			24		A
$Q_{rr}$	Reverse Recovery Charge			770		nC



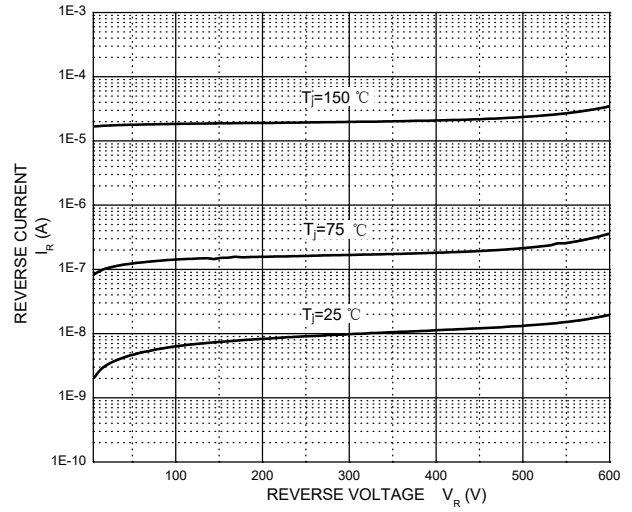
Reverse Recovery Waveform and Definitions

# Typical Characteristics

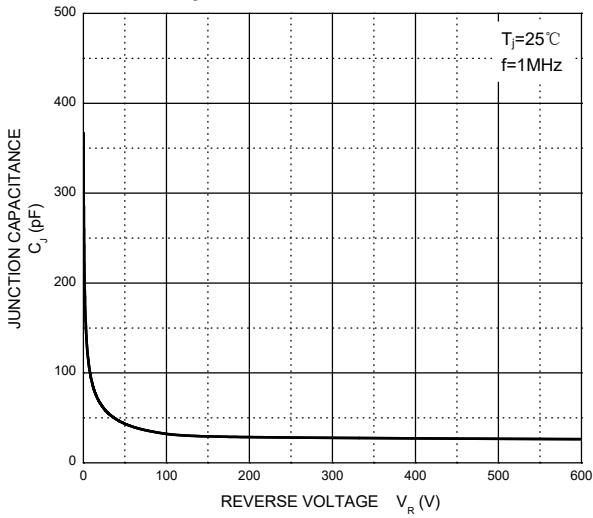
### Forward Characteristics



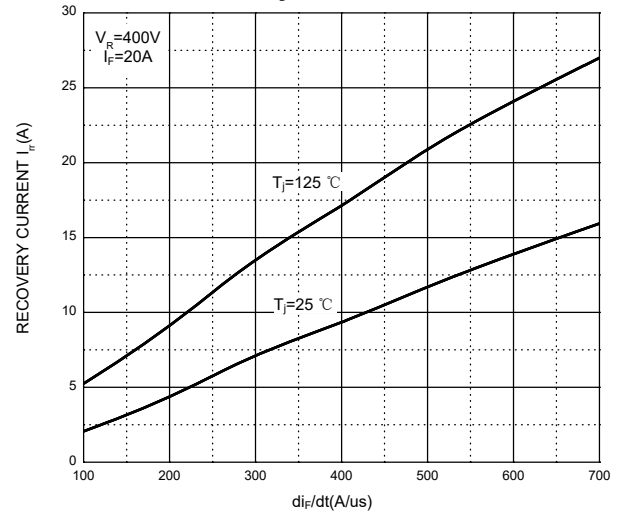
### Reverse Characteristics



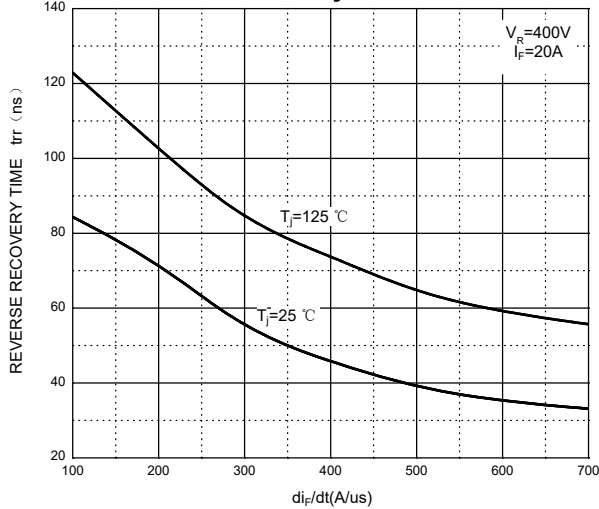
### Capacitance Characteristics



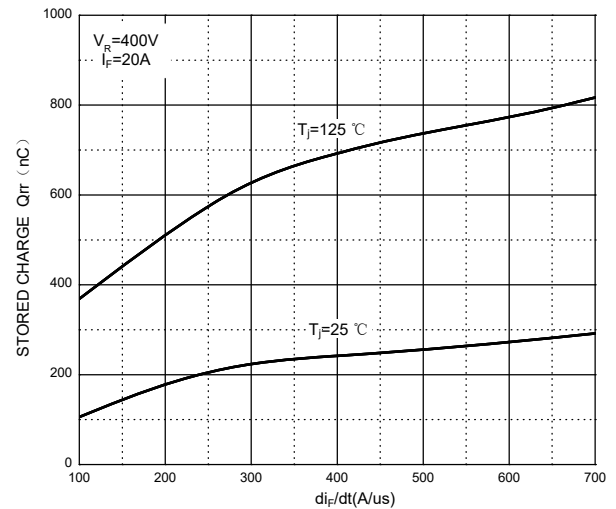
### Recovery Current vs. $di_F/dt$



### Reverse Recovery Time vs. $di_F/dt$

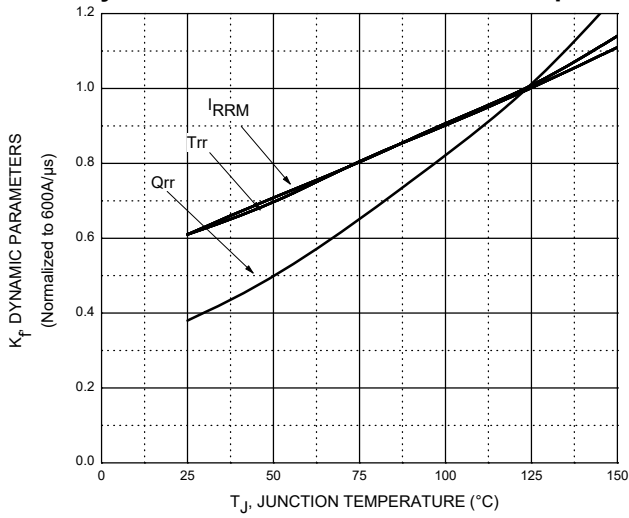


### Stored Charge vs. $di_F/dt$

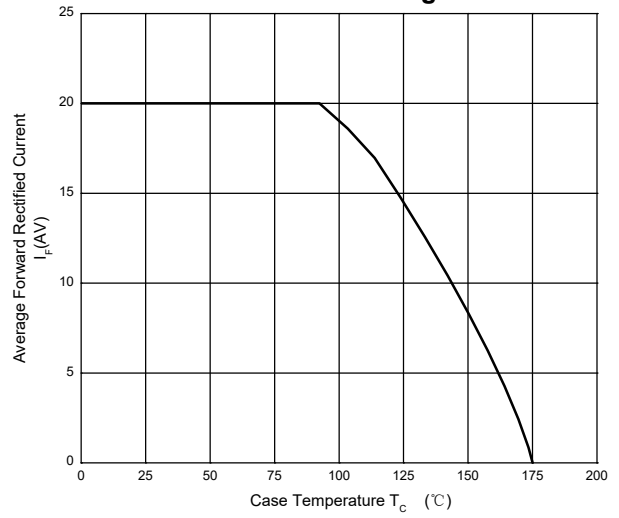


# Typical Characteristics

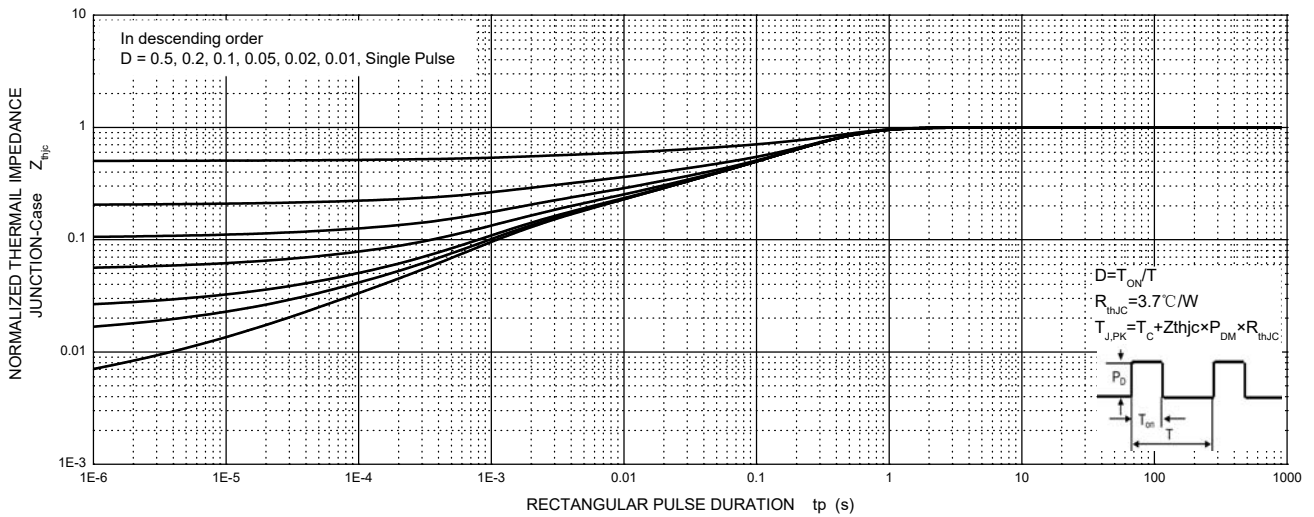
### Dynamic Parameters vs. Junction Temperature



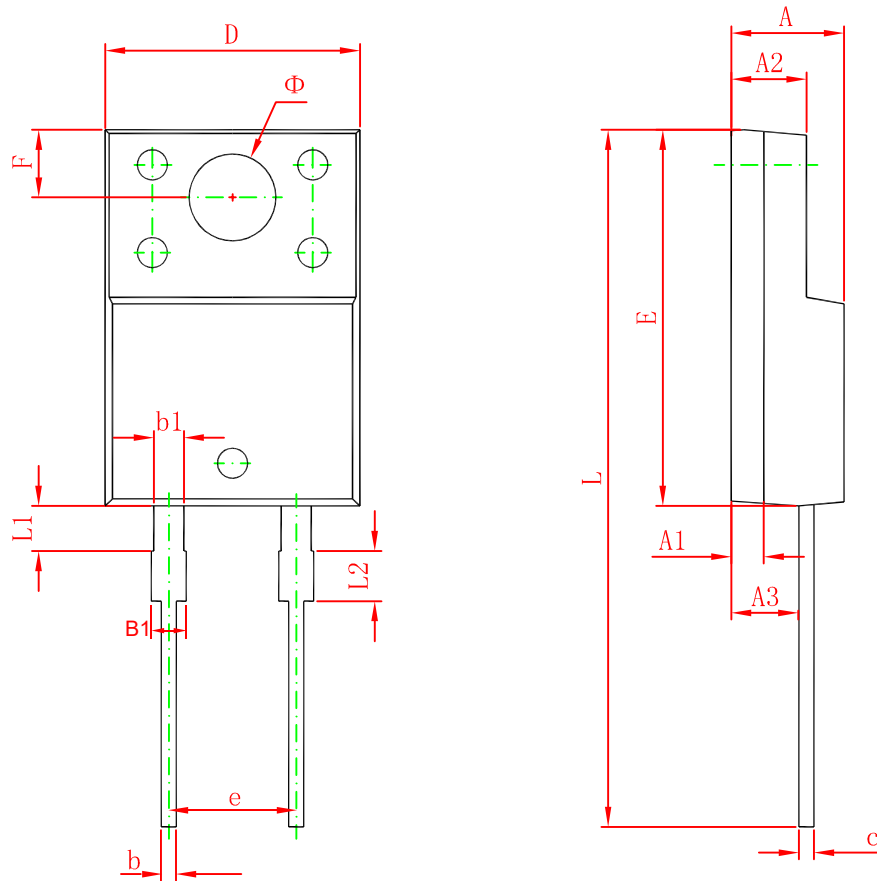
### Current Derating



### MURF20H60L Transient Thermal Impedance, Junction-Case



# TO-220F-2L Package Outline Dimensions



Symbol			Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.300	4.700	0.169	0.185
A1	1.200 REF.		0.047 REF.	
A2	2.800	3.200	0.110	0.126
A3	2.500	2.900	0.098	0.114
b	0.710	0.910	0.028	0.036
b1	1.100	1.350	0.043	0.053
B1	1.150	1.400	0.045	0.055
c	0.500	0.750	0.020	0.030
D	9.960	10.360	0.392	0.408
E	14.800	15.200	0.583	0.598
e	5.080 TYP.		0.200 TYP.	
F	2.700 REF.		0.106 REF.	
$\Phi$	3.300 REF.		0.130 REF.	
L	28.000	28.400	1.102	1.118
L1	2.100	2.400	0.082	0.094
L2	1.300	1.700	0.051	0.066